

PN4917



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PNP General Purpose Amplifier

This device is designed for use as general purpose amplifiers and switches requiring collector currents to 100 mA. Sourced from Process 66. See 2N3906 for characteristics.

Absolute Maximum Ratings* TA = 25°C unless otherwise noted

Symbol	Parameter	Value	Units
V_{CEO}	Collector-Emitter Voltage	30	V
V _{CBO}	Collector-Base Voltage	30	V
V _{EBO}	Emitter-Base Voltage	5.0	V
I _C	Collector Current - Continuous	200	mA
T _J , T _{stg}	Operating and Storage Junction Temperature Range	-55 to +150	°C

*These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

NOTES:

1) These ratings are based on a maximum junction temperature of 150 degrees C.
2) These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

Thermal Characteristics

Thermal Characteristics TA = 25°C unless otherwise noted				
Symbol	Characteristic	Max	Units	
		PN4917		
P _D	Total Device Dissipation Derate above 25°C	625 5.0	mW mW/°C	
$R_{\theta JC}$	Thermal Resistance, Junction to Case	83.3	°C/W	
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	200	°C/W	

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PNP General Purpose Amplifier

Symbol	Parameter	Test Conditions	Min	Мах	Units
OFF CHA	RACTERISTICS				
V _{(BR)CEO}	Collector-Emitter Breakdown Voltage*	$I_{\rm C} = 10 \text{ mA}, I_{\rm B} = 0$	30		V
V _{(BR)CBO}	Collector-Base Breakdown Voltage	$I_{\rm C} = 10 \ \mu {\rm A}, I_{\rm E} = 0$	30		V
V _{(BR)EBO}	Emitter-Base Breakdown Voltage	$I_{E} = 10 \ \mu A, I_{C} = 0$	5.0		V
V _{(BR)CES}	Collector-Emitter Breakdown Voltage	I _c = 10 μA	30		V
I _B	Base Cutoff Current	V _{CE} = 15 V		25	nA
I _{CES}	Collector Cutoff Current	V _{CE} = 15 V		25	nA
		$V_{CE} = 15 \text{ V}, \text{T}_{A} = 65 ^{\circ}\text{C}$		25	μA
h _{FE}	DC Current Gain	$ \begin{array}{l} V_{CE} = 1.0 \ V, \ I_{C} = 100 \ \mu A \\ V_{CE} = 1.0 \ V, \ I_{C} = 1.0 \ mA \\ V_{CE} = 1.0 \ V, \ I_{C} = 10 \ mA \\ V_{CE} = 1.0 \ V, \ I_{C} = 50 \ mA \end{array} $	100 150 150 30	300	
V _{CE(sat)}	Collector-Emitter Saturation Voltage	$I_{c} = 1.0 \text{ mA}, I_{B} = 0.1 \text{ mA}$ $I_{c} = 10 \text{ mA}, I_{B} = 1.0 \text{ mA}$ $I_{c} = 50 \text{ mA}, I_{B} = 5.0 \text{ mA}$		0.13 0.14 0.30	V V V
V _{BE(sat)}	Base-Emitter Saturation Voltage	$I_{C} = 1.0 \text{ mA}, I_{B} = 0.1 \text{ mA}$ $I_{C} = 10 \text{ mA}, I_{B} = 1.0 \text{ mA}$ $I_{C} = 50 \text{ mA}, I_{B} = 5.0 \text{ mA}$	0.70 0.75	0.75 0.90 1.10	V V V
SMALL S	IGNAL CHARACTERISTICS				
Cob	Output Capacitance	V _{CB} = 10 V, f = 1.0 MHz		4.5	pF
C _{ib}	Input Capacitance	V _{EB} = 0.5 V, f = 1.0 MHz		8.0	pF
		1		i	+
h _{fe} rb'Cc	Small-Signal Current Gain	$I_{c} = 10 \text{ mA}, V_{CE} = 20 \text{ V},$ f = 100 MHz $V_{CE} = 20 \text{ V}, I_{c} = 10 \text{ mA}$	4.5		

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h _{FE}	DC Current Gain	$V_{CE} = 1.0 \text{ V}, I_{C} = 100 \mu\text{A}$	100		
		$V_{CE} = 1.0 \text{ V}, I_{C} = 1.0 \text{ mA}$	150		
		$V_{CE} = 1.0 \text{ V}, I_{C} = 10 \text{ mA}$	150	300	
		$V_{CE} = 1.0 \text{ V}, I_{C} = 50 \text{ mA}$	30		
V _{CE(sat)}	Collector-Emitter Saturation Voltage	$I_{\rm C} = 1.0 \text{ mA}, I_{\rm B} = 0.1 \text{ mA}$		0.13	V
()		$I_{\rm C} = 10 \text{ mA}, I_{\rm B} = 1.0 \text{ mA}$		0.14	V
		$I_{\rm C} = 50 \text{ mA}, I_{\rm B} = 5.0 \text{ mA}$		0.30	V
V _{BE(sat)}	Base-Emitter Saturation Voltage	$I_{\rm C} = 1.0 \text{ mA}, I_{\rm B} = 0.1 \text{ mA}$		0.75	V
()		$I_{\rm C} = 10 \text{ mA}, I_{\rm B} = 1.0 \text{ mA}$	0.70	0.90	V
		$I_{\rm C} = 50 \text{ mA}, I_{\rm B} = 5.0 \text{ mA}$	0.75	1.10	V

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C _{ob}	Output Capacitance	$V_{CB} = 10 \text{ V}, \text{ f} = 1.0 \text{ MHz}$		4.5	pF
C _{ib}	Input Capacitance	V _{EB} = 0.5 V, f = 1.0 MHz		8.0	pF
h _{fe}	Small-Signal Current Gain	$I_{C} = 10 \text{ mA}, V_{CE} = 20 \text{ V},$ f = 100 MHz	4.5		
rb'Cc	Collector-Base Time Constant	$V_{CE} = 20 \text{ V}, \text{ I}_{C} = 10 \text{ mA}$ f = 80 MHz		50	ps
NF	Noise Figure	$V_{CE} = 5.0 \text{ V}, \text{ I}_{C} = 1.0 \text{ mA},$ $R_{S} = 100 \Omega, \text{ f} = 100 \text{ MHz}$ $V_{CE} = 5.0 \text{ V}, \text{ I}_{C} = 100 \text{ \muA},$		6.0	dB
		$R_s = 1.0 \text{ k}\Omega$		4.0	dB

SWITCHING CHARACTERISTICS

t _{on}	Turn-on Time	$V_{CC} = 10 \text{ V}, \text{ I}_{C} = 50 \text{ mA},$	40	ns
t _d	Delay Time	I _{B1} = 5.0 mA	15	ns
tr	Rise Time		40	ns
t _{off}	Turn-off Time	$V_{CC} = 10 \text{ V}, \text{ I}_{C} = 50 \text{ mA}$	150	ns
ts	Storage Time	$I_{B1} = I_{B2} = 5.0 \text{ mA}$	140	ns
t _f	Fall Time		40	ns

*Pulse Test: Pulse Width ${\leq}\,300\,\mu\text{s},$ Duty Cycle ${\leq}\,2.0\%$

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